Electronic Supplementary Information

The growth of large GdPO⁴ crystal guided by theoretical simulation

and the study of its phonon properties

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1. Computational details

1.1. Surface energies and lattice dynamics calculation details

In this work, all the first-principle calculations were performed on the basis of the density functional theory (DFT). 1 The projector augmented wave (PAW) pseudopotentials with the *f* electrons treated as core states were applied to describe the electron-ion interactions.2,3 The Generalized Gradient Approximation (GGA) with the Perdew-Burke-Ernzerhof functional for solids (PBEsol) was used to express the exchange-correlation potential. An energy cutoff of 520 eV and appropriate k-point meshes were chosen to ensure the convergence of the total energy in 1 meV per formula unit. The structure relaxations were performed with a force convergence criterion of 0.03 eV/ \AA for the surface energies calculation. The convergence precision for the lattice dynamics calculation was 1×10^{-8} eV/Å.

1.2. Structural relaxation

The structure data of $GdPO₄$ was obtained from the Inorganic Crystal Structure Database with ICSD ID: 79753.⁴ The experimental structural parameters were relaxed before used for all further calculations. In this work, all calculations and analyses are based on the standardized crystal structure data of $GdPO₄$, in which the relaxed lattice parameters are *a* = 6.310 Å, *b* = 6.823 Å, *c* = 7.951 Å, *α* = *γ* = 90.00°, and *β* = 126.15°, and in good agreement with the experimental ones. $4-7$

1.3. Obtaining free energy change

The free energy of a substance can be calculated by the first-principle method, and then the free energy change of a chemical reaction can be obtained by using Eq. (3) in section 2.1. The free energy for most common compounds are available in the database of the Materials Project, 8 which is built on the first-principle methods. Thus we predicted the possible chemical reaction equation according to the proportion of reactants and searched the free energy of each substance in the database to estimate the change of the free energy, $\Delta F[c; a, b]$.

2. Supplementary Figures

Figure S1 The determined (001) surface (pink solid line) of GdPO₄ with an O atom located on the crystal plane. The blue dotted lines represent Gd-O bonds and the black solid lines are P-O bonds.

Figure S2 The structure of the (010) surface of GdPO₄ with an O atom located on the crystal plane.

Figure S3 The structure of the (-101) surface of GdPO₄ with an O atom located on the crystal plane.

Figure S4 The structure of the (011) surface of GdPO₄ with an O atom located on the crystal plane.

Figure S5 The structure of the (-102) surface of GdPO₄ with a Gd atom located on the crystal plane.

Figure S6 The structure of the (-111) surface of GdPO₄ with a Gd atom located on the crystal plane.

Figure S7 Calculated atomic displacements for some modes of GdPO₄ with experimental frequencies in wavenumbers.

Figure S8 Temperature-dependent Raman frequencies in wavenumbers for the selected peaks, the peaks were denoted by their peak positions according to Figure 5. (a) 235 cm⁻¹, (b) 475 cm⁻¹, (c) 630 cm⁻¹ and (d) 988 $cm⁻¹$. The red solid curves are fitted ones according to Eq. (5).

3. Supplementary Tables

Table S1 Candidate atomic planes, each defined by a crystal plane and an atom located on it, and the number of broken Gd-O bonds a plane cuts.

Surfaces	Atoms on the surfaces		a	\boldsymbol{b}	\pmb{C}	γ
(001)	O(0.340, 0.102, 0.027)		6.29	6.81	16.08	90.00°
(010)	O(0.184, 0.001, 0.246)		6.29	6.62	16.81	104.17°
	O(0.119, 0.165, 0.616)		6.29	6.62	18.01	104.17°
(-101)	O (0.660,0.898,0.973)		6.62	6.81	16.92	90.00°
(011)	O(0.119, 0.165, 0.616)		6.29	9.50	15.53	99.82°
(-102)	Gd (0.815,0.345,0.719)		6.81	10.19	13.00	90.00°
(-111)	Gd (0.185,0.845,0.782)		6.62	9.27	14.02	99.55°
	0 (0.881,0.665,0.884)		6.62	9.27	16.37	99.55°
	O (0.185,0.499,0.746)		6.62	9.27	16.51	99.55°
(100)	0 (0.881,0.835,0.384)		6.81	7.94	13.90	90.00°
(-112)	O(0.815, 0.501, 0.254)		9.27	9.50	15.59	114.27°
(110)	O(0.406, 0.786, 0.619)		7.94	9.27	13.81	113.49°
	Gd (0.185,0.845,0.782)		7.94	9.27	16.57	113.49°
	Table S3 Surface energies of the GdPO ₄ crystal.					
Surfaces	(010)	(011)	(001)		(-102)	(-101)
E_s (J/m ²)	0.752	0.707	0.783		1.143	1.202
Surfaces	(-111)	(100)	(110)		(-112)	
E_s (J/m ²)	1.412	2.197	3.057		3.644	

Table S2 The unit cell parameters of the slab models for determining the surfaces, each unit cell contains the same number of atoms as that of the bulk GdPO₄.

Modes	Calculated Raman frequency (cm-1)		
$B_g(v_3)$	1064		
$A_g(v_3)$	1047		
$B_g(v_3)$	1043		
$B_g(v_3)$	1012		
$A_g(v_3)$	1001		
$A_g(v_3)$	977		
$B_g(v_1)$	948		
$A_g(v_1)$	938		
$A_g(v_4)$	607		
$B_g(v_4)$	604		
$A_g(v_4)$	567		
$B_g(v_4)$	546		
$A_g(v_4)$	537		
$B_g(v_4)$	509		
$A_g(v_2)$	501		
$A_g(v_2)$	459		
$A_g(v_2)$	407		
$B_g(v_2)$	384		
$A_g(R)$	310		
$B_g(T)$	296		
$B_g(T)$	277		
$A_g(T)$	266		
$B_g(T)$	246		
$A_g(R)$	240		
$B_g(R)$	234		
$A_g(T)$	191		
$A_g(T)$	189		
$B_g(R)$	182		
$A_g(R)$	178		
$B_g(R)$	156		
$B_g(T)$	136		
$B_g(T)$	129		
$A_g(R)$	124		
$A_g(T)$	108		
$A_g(T)$	86		
$B_g(R)$	84		

Table S4 The calculated Raman frequencies of GdPO₄ and the assignments for the modes.

 \overline{a}

Table S5 The values of the fitted parameters $A^{'}$, $\omega_0^{'}$ and ω' of Eq.(5), the units of these values were given in

the parentheses in the first row, respectively.							
Peaks $(cm-1)$	'cm ^{−⊥} A	\sim (CM ⁻¹⁾ ω_{0}	$\mathfrak{m}^{\mathfrak{m}}$ ω				
235	-7.09	244.40	286.38				
475	-13.12	482.36	828.57				
630	-7.46	638.69	406.95				
988	-15.79	993.71	566.21				

4. References

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